

# The effect of atomic-scale defects and dopants on Graphene electronic structure

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**GraphITA**  
**GSNL, Assergi (L'Aquila), May 15<sup>th</sup> - 18<sup>rd</sup> 2011**

# Outline

- 1 Introduction
- 2 Hydrogen adsorption
- 3 Bandgap engineering

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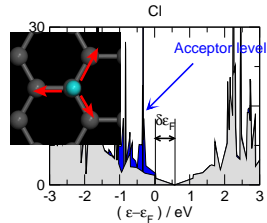
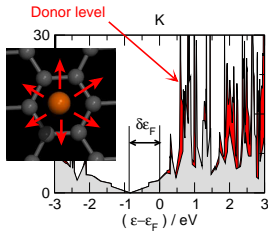
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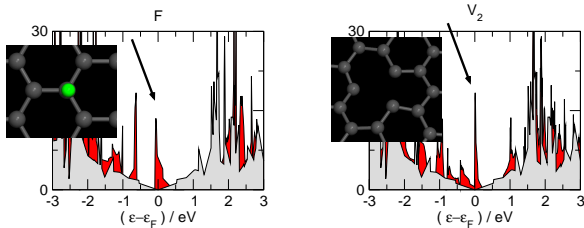
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# Ionic binding



- DOSs are unchanged except for **donor**/**acceptor** levels
- **electron** / **hole** doping
- Atomic species are **mobile**
- **Li, Na, K, Cs..** vs **Cl, Br, I, ..**

# Covalent binding

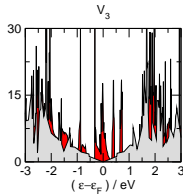
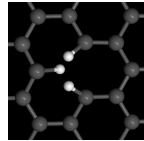
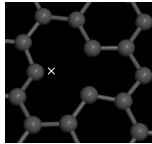
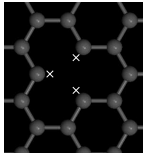


- Midgap states show up in the DOSs
- Atomic species are immobile
- H, F, OH, CH<sub>3</sub>, etc. behave similarly to vacancies

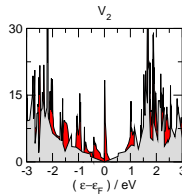
See e.g., T. O. Wehling, M. I. Katsnelson and A. I. Lichtenstein, *Phys. Rev. B* **80**, 085428 (2008)



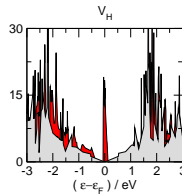
# Vacancies vs adatoms



Unrelaxed



Relaxed



Saturated

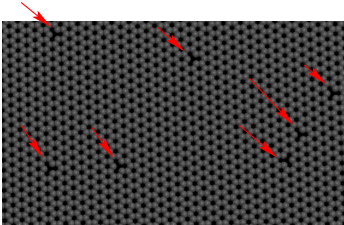
See e.g., F. Banhart, J. Kotakoski, A. V. Krasheninnikov, *ACS Nano* **5**, 26 (2011)



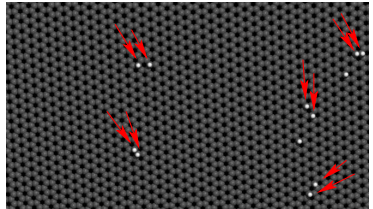


# Vacancies vs adatoms

High-energy  $e^-$ /ion beams  
⇒ **Random** arrangement



Low-energy beams (kinetic control)  
⇒ **Clustering** due to preferential sticking



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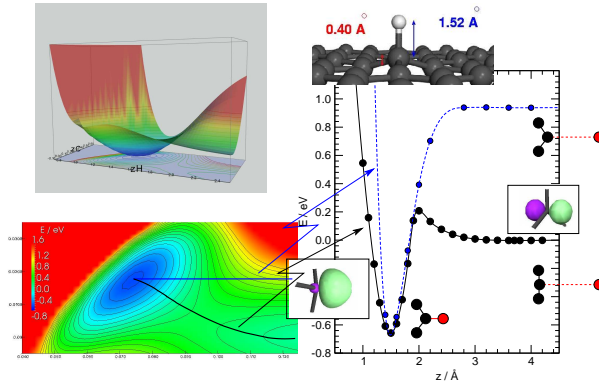
# Hydrogen chemisorption on graphene

- Sticking is thermally **activated**<sup>1,2</sup>
- **Midgap** states are generated upon sticking
- Diffusion of chemisorbed species does **not** occur<sup>3,4</sup>
- **Preferential** sticking and clustering<sup>3,5,6</sup>

- [1] L. Jelaica and V. Sidis, *Chem. Phys. Lett.* **300**, 157 (1999)  
[2] X. Sha and B. Jackson, *Surf. Sci.* **496**, 318 (2002)  
[3] L. Hornekaer *et al.*, *Phys. Rev. Lett.* **97**, 186102 (2006)  
[4] J. C. Meyer *et al.*, *Nature* **454**, 319 (2008)  
[5] A. Andree *et al.*, *Chem. Phys. Lett.* **425**, 99 (2006)  
[6] L. Hornekaer *et al.*, *Chem. Phys. Lett.* **446**, 237 (2007)



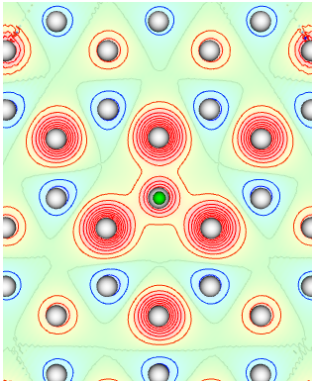
# Sticking



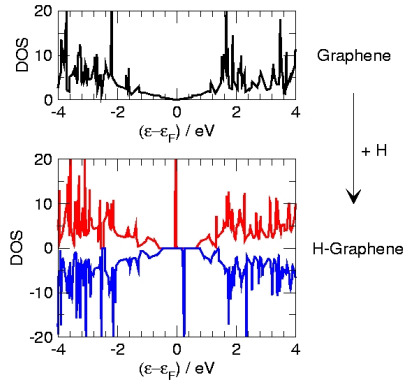
L. Jelaica and V. Sidis, *Chem. Phys. Lett.* **300**, 157 (1999)  
X. Sha and B. Jackson, *Surf. Sci.* **496**, 318 (2002)



# Midgap states



..patterned spin-density



# Midgap states

$$H^{TB} = \sum_{\sigma, ij} (t_{ij} a_{i,\sigma}^\dagger b_{j,\sigma} + t_{ji} b_{j,\sigma}^\dagger a_{i,\sigma})$$

## Electron-hole symmetry

$$b_i \rightarrow -b_i \implies \mathbf{h} \rightarrow -\mathbf{h}$$

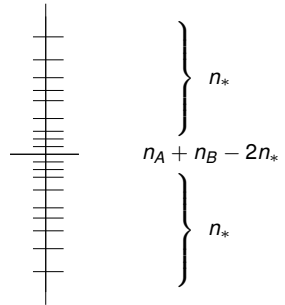
if  $\epsilon_i$  is eigenvalue and

$$c_i^\dagger = \sum_j \alpha_j a_j^\dagger + \sum_j \beta_j b_j^\dagger \text{ eigenvector}$$

$\Downarrow$

$-\epsilon_i$  is also eigenvalue and

$$c_i'^\dagger = \sum_j \alpha_j a_j^\dagger - \sum_j \beta_j b_j^\dagger \text{ is eigenvector}$$



# Midgap states

$$H^{TB} = \sum_{\tau, ij} (t_{ij} a_{i,\tau}^{\dagger} b_{j,\tau} + t_{ji} b_{j,\tau}^{\dagger} a_{i,\tau})$$

## Theorem

If  $n_A > n_B$  there exist (at least)  $n_I = n_A - n_B$  "midgap states" with vanishing components on B sites

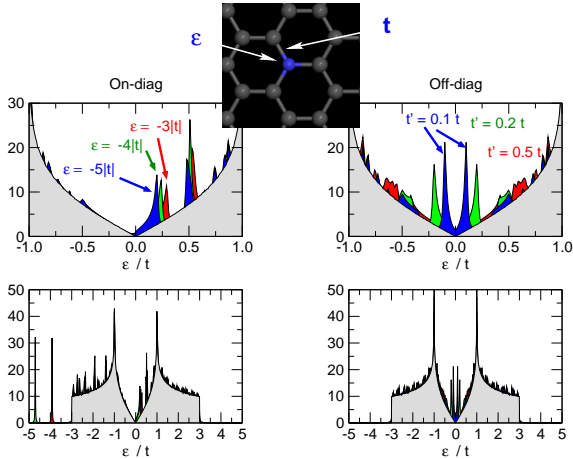
## Proof.

$$\begin{bmatrix} \mathbf{0} & \mathbf{T}^{\dagger} \\ \mathbf{T} & \mathbf{0} \end{bmatrix} \begin{bmatrix} \alpha \\ \beta \end{bmatrix} = \begin{bmatrix} \mathbf{0} \\ \mathbf{0} \end{bmatrix} \text{ with } \mathbf{T} \text{ } n_B \times n_A ( > n_B )$$

$\implies \mathbf{T}\alpha = \mathbf{0}$  has  $n_A - n_B$  solutions



# Midgap states

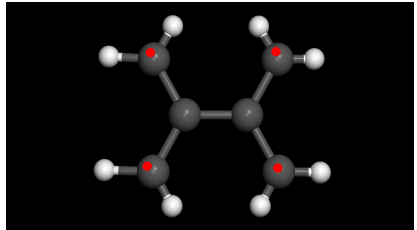




# Midgap states

## Counting the midgap states

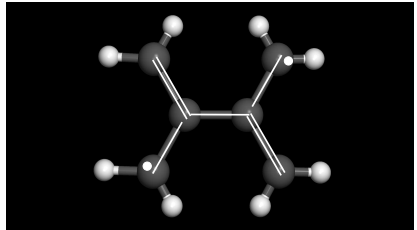
- **Maximal** set(s) of **non-adjacent** sites,  $\mathcal{A}$
- $\eta_{\mathcal{A}} = \text{card}\{\mathcal{A}\},$   
 $n_I = 2\eta_{\mathcal{A}} - N$
- $\eta_{\mathcal{A}} \geq n_A \Rightarrow n_I \geq n_A - n_B$



# Midgap states

## Counting the midgap states

- **Maximal** set(s) of **non-adjacent** sites,  $\mathcal{A}$
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# Midgap states

$$H^{Hb} = \sum_{\tau, ij} (t_{ij} a_{i,\tau}^\dagger b_{j,\tau} + t_{ji} b_{j,\tau}^\dagger a_{i,\tau}) + U \sum_i n_{i,\tau} n_{i,-\tau}$$

## Theorem

If  $U > 0$ , the ground-state at half-filling has

$$S = |n_A - n_B|/2 = n_I/2$$

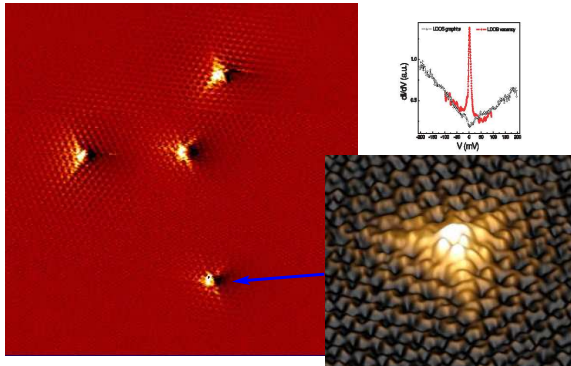
## Proof.

E.H. Lieb, *Phys. Rev. Lett.* **62**, 1201 (1989)



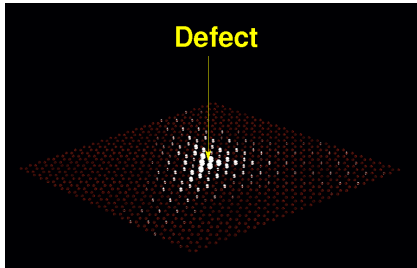
...basically, we can apply **Hund's rule** to previous result

# Midgap states for isolated “defects”



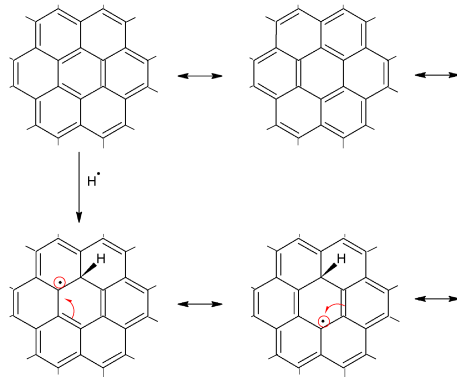
M.M. Ugeda, I. Brihuega, F. Guinea and J.M. Gomez-Rodriguez, *Phys. Rev. Lett.* **104**, 096804 (2010)

# Midgap states for isolated “defects”

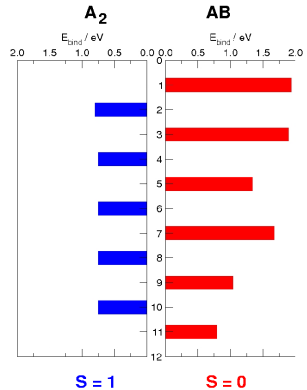
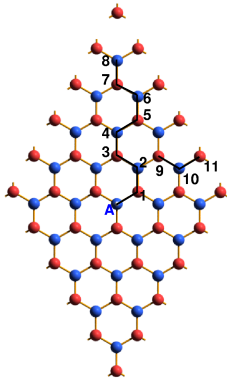


$$\psi(x, y, z) \sim 1/r$$

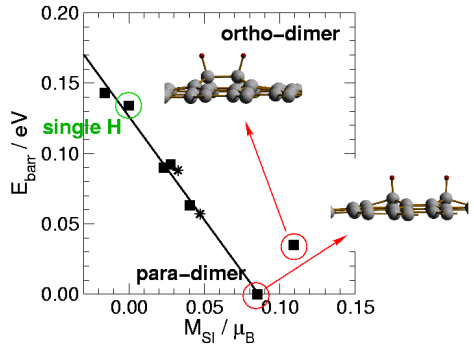
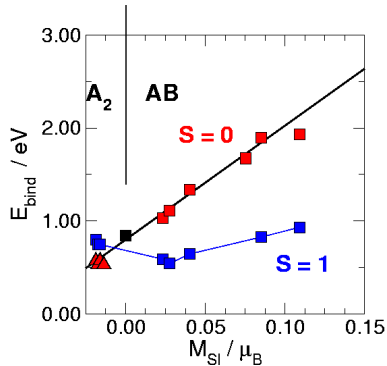
V. M. Pereira *et al.*, *Phys. Rev. Lett.* **96**, 036801 (2006);  
*Phys. Rev. B* **77**, 115109 (2008)



# Dimers



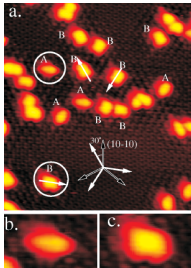
# Dimers



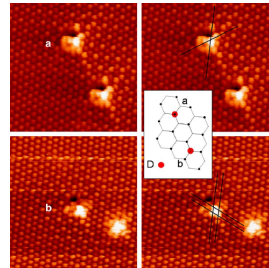
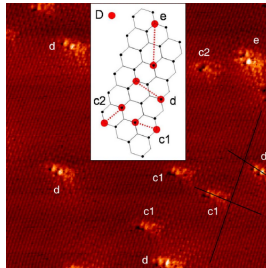
S. Casolo, O.M. Lovvik, R. Martinazzo and G.F. Tantardini, *J. Chem. Phys.* **130** 054704 (2009)



# Dimers



[1]



[2]

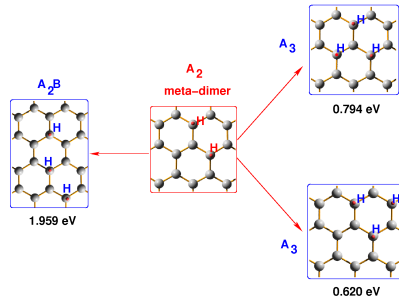
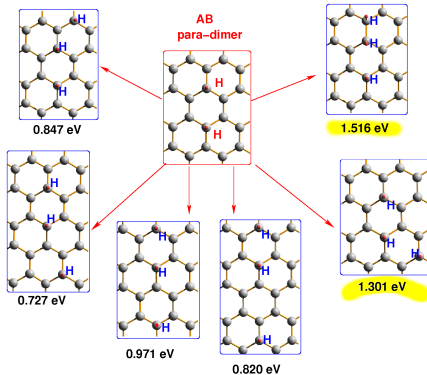
[1] L. Hornekaer, Z. Sljivancanin, W. Xu, R. Otero, E. Rauls, I. Stensgaard, E. Laegsgaard, B. Hammer and F. Besenbacher. *Phys. Rev. Lett.* **96** 156104 (2006)

[2] A. Andree, M. Le Lay, T. Zecho and J. Kupper, *Chem. Phys. Lett.* **425** 99 (2006)





# Clusters

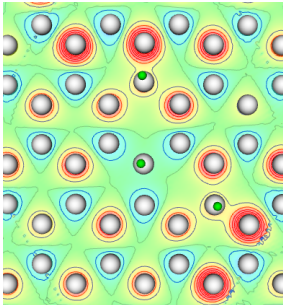


$$\mu = 1\mu_B \Rightarrow \mu = 2\mu_B \Rightarrow \mu = 3\mu_B$$

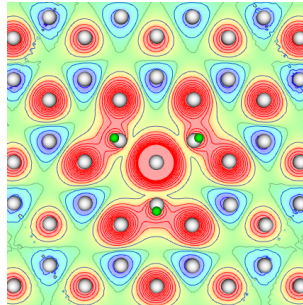


# Clusters

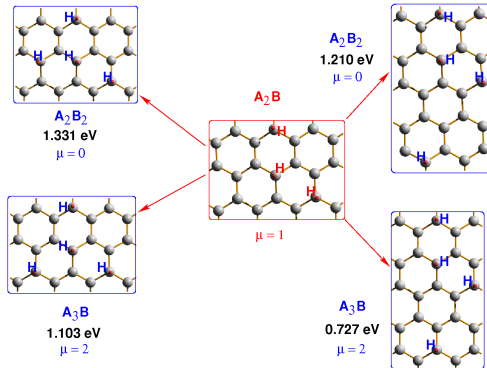
$A_2B$



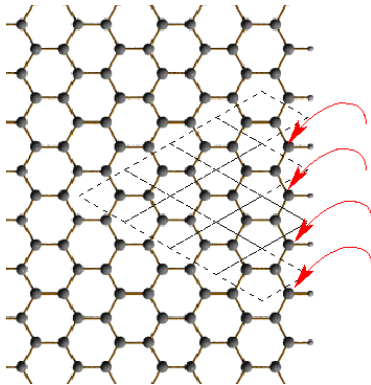
$A_3$



# Clusters

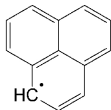


# Role of edges

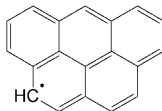


- *zig-zag* edge sites have **enhanced** hydrogen affinity
- **geometric** effects can be investigated in small graphenes

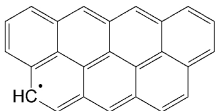
# Role of edges



perinaphthenylene / fenalene

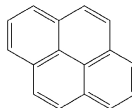


benzo[cd]pirenyle

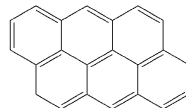


7 - PAH

imbalanced 'PAHs'



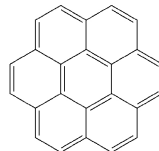
pirene



dibenzo[def,mno]crisene /  
antrantrene



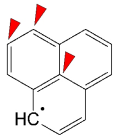
benzo[ghi]perilene



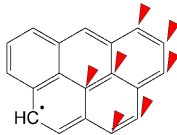
coronene

balanced PAHs

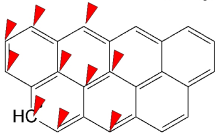
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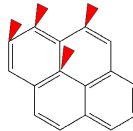


benzo[cd]pirene

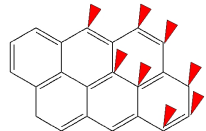


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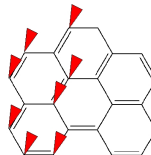
imbalanced 'PAHs'



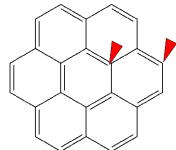
perylene



dibenzo[def,mno]crisene /  
antranthrene



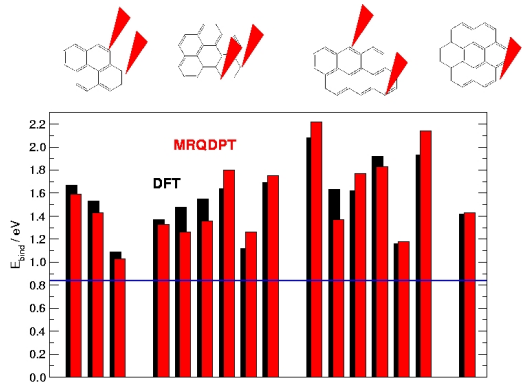
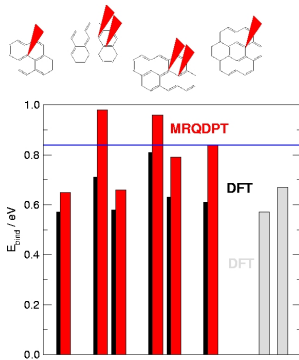
benzo[ghi]perylene



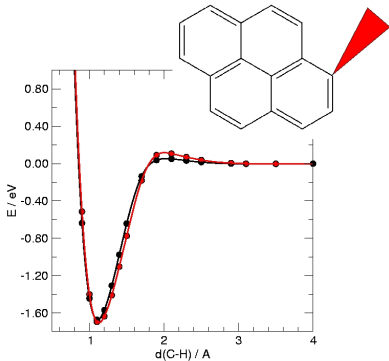
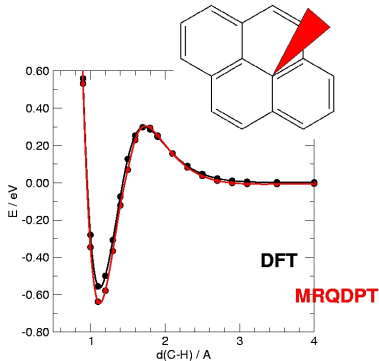
coronene

balanced PAHs

# Role of edges: graphenic vs edge sites



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# Band-gap opening

- **Electron confinement**: nanoribbons, (nanotubes), etc.
- **Symmetry breaking**: epitaxial growth, deposition, etc.
- **Symmetry preserving**: “supergraphenes”

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# e-h symmetry

$$H^{TB} = \sum_{\sigma,ij} (t_{ij} a_{i,\sigma}^{\dagger} b_{j,\sigma} + t_{ji} b_{j,\sigma}^{\dagger} a_{i,\sigma})$$

## Electron-hole symmetry

$$b_i \rightarrow -b_i \implies \mathbf{h} \rightarrow -\mathbf{h}$$

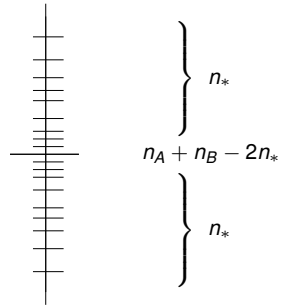
if  $\epsilon_i$  is eigenvalue and

$$c_i^{\dagger} = \sum_i \alpha_i a_i^{\dagger} + \sum_j \beta_j b_j^{\dagger} \text{ eigenvector}$$

$\Downarrow$

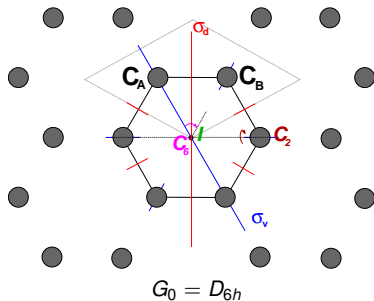
$-\epsilon_i$  is also eigenvalue and

$$c_i'^{\dagger} = \sum_i \alpha_i a_i^{\dagger} - \sum_j \beta_j b_j^{\dagger} \text{ is eigenvector}$$

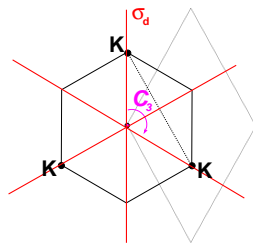


# Spatial symmetry

***r*-space**



***k*-space**

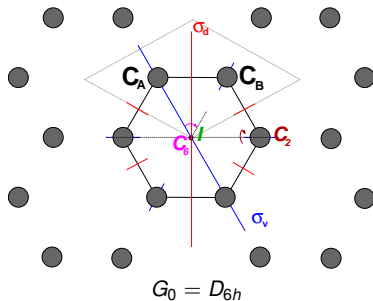


$$G(\mathbf{k}) = \{g \in G_0 | g\mathbf{k} = \mathbf{k} + \mathbf{G}\}$$

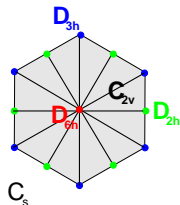
$$\Rightarrow G(\mathbf{K}) = D_{3h}$$

# Spatial symmetry

***r*-space**



***k*-space**

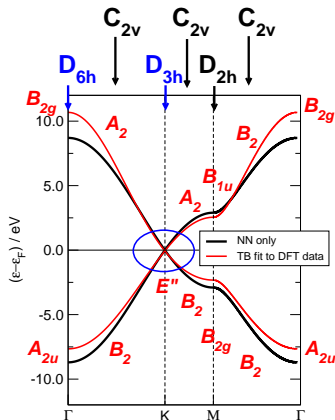


$$G(\mathbf{k}) = \{g \in G_0 | g\mathbf{k} = \mathbf{k} + \mathbf{G}\}$$

$$\Rightarrow G(\mathbf{K}) = D_{3h}$$



# Spatial symmetry



$$|A_{\mathbf{k}}\rangle = \frac{1}{\sqrt{N_{BK}}} \sum_{\mathbf{R} \in BK} e^{-i\mathbf{k}\mathbf{R}} |A_{\mathbf{R}}\rangle$$

$$|B_{\mathbf{k}}\rangle = \frac{1}{\sqrt{N_{BK}}} \sum_{\mathbf{R} \in BK} e^{-i\mathbf{k}\mathbf{R}} |B_{\mathbf{R}}\rangle$$

$$\langle r | A_{\mathbf{R}} \rangle = \phi_{p_z}(\mathbf{r} - \mathbf{R})$$

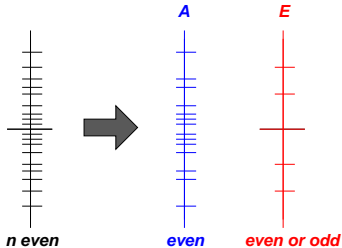
For  $\mathbf{k} = \mathbf{K}$  (or  $\mathbf{K}'$ )

- $\{|A_{\mathbf{k}}\rangle, |B_{\mathbf{k}}\rangle\}$  span the  $E''$  irrep of  $D_{3h}$
- Degeneracy is lifted at **first order** (no  $i$  symmetry in  $D_{3h}$ )





# Spatial and $e-h$ symmetry



## Lemma

*$e-h$  symmetry holds within each kind of symmetry species (A, E, ..)*

## Theorem

*For any bipartite lattice at **half-filling**, if the number of **E** irreps is **odd** at a special point, there is a degeneracy **at the Fermi level**, i.e.  $E_{\text{gap}} = 0$*

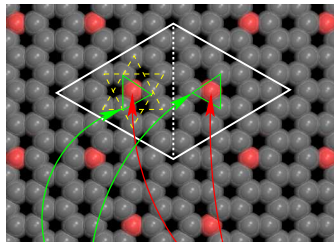
# A simple recipe

- Consider  $nxn$  graphene **superlattices** (i.e.  $G = D_{6h}$ ):  
degeneracy is expected at  $\Gamma$ , K
- Introduce  $p_z$  vacancies while **preserving** point symmetry
- Check whether it is possible to turn the **number of  $E$  irreps**  
to be **even both** at  $\Gamma$  **and** at K



# Counting the number of $E$ irreps

$$n = 4$$



$\Gamma$ :  $2A + 2E$   
 $K$ :  $2A + 2E$

$\Gamma$ :  $2A$   
 $K$ :  $E$

$\Gamma$	A	E
$\bar{0}_3$	$2m^2$	$2m^2$
$\bar{1}_3$	$2(3m^2 + 2m + 1)$	$2(3m^2 + 2m)$
$\bar{2}_3$	$2(3m^2 + 4m + 2)$	$2(3m^2 + 4m + 1)$

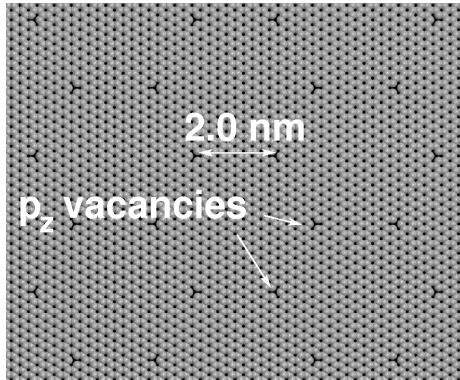
$K_n$	A	E
$\bar{0}_3$	$2m^2$	$2m^2$
$\bar{1}_3$	$2m(3m + 2)$	$2m(3m + 2) + 1$
$\bar{2}_3$	$2(3m^2 + 4m + 1)$	$2(3m^2 + 4m + 1) + 1$

$$\Rightarrow n = 3m + 1, 3m + 2, m \in \mathbb{N}$$



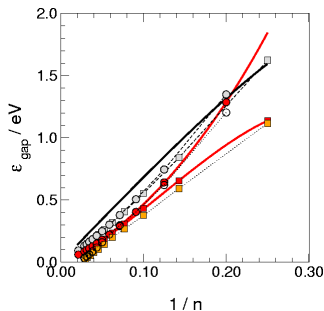
# An example

**(14,0)-honeycomb**



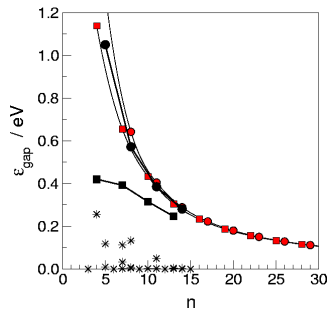
# Band-gap opening..

## Tight-binding



$$\epsilon_{\text{gap}}(K) \sim 2t\sqrt{1.683}/n$$

## DFT

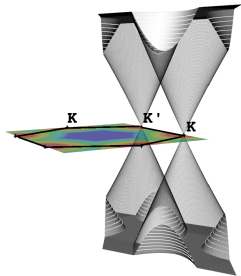


R. Martinazzo, S. Casolo and G.F. Tantardini, *Phys. Rev. B*, **81** 245420 (2010)

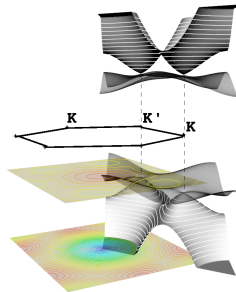


## ..and Dirac cones

..not only: as degeneracy may still occur at  $\epsilon \neq \epsilon_F$   
**new Dirac points** are expected



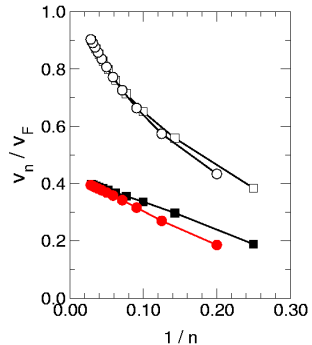
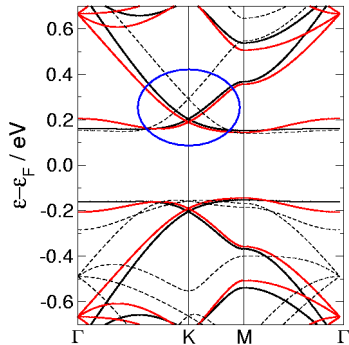
graphene (4x4)



(4,0)-honeycomb

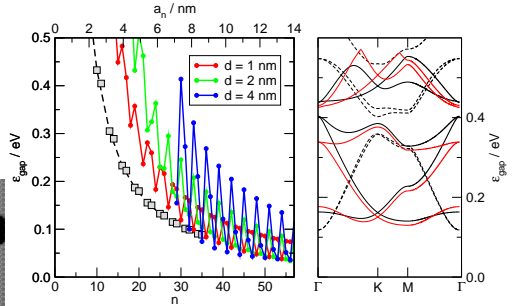
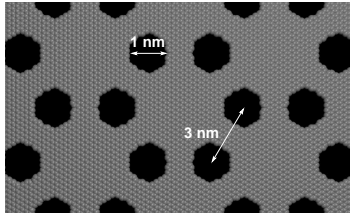
## ..and Dirac cones

..not only: as degeneracy may still occur at  $\epsilon \neq \epsilon_F$   
new Dirac points are expected



# Antidot superlattices

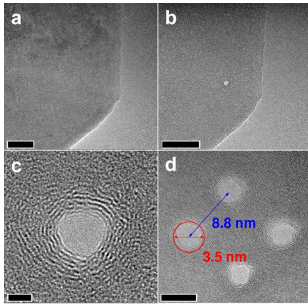
...the same holds for **honeycomb antidots**





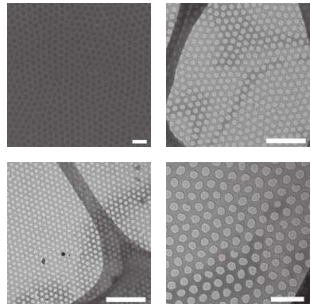
# Antidot superlattices

...the same holds for **honeycomb antidots**



M. D. Fishbein and M. Drndic, *Appl. Phys. Lett.* **93**, 113107 (2008)

T. Shen *et al.* *Appl. Phys. Lett.* **93**, 122102 (2008)



J. Bai *et al.* *Nature Nanotech.* **5**, 190 (2010)

# Summary

- **Covalently bound** species generate midgap species upon bond formation
- **Midgap states** affect chemical reactivity
- Thermodynamically and kinetically favoured configurations **minimize** sublattice imbalance
- Symmetry *breaking* is **not** necessary to open a gap

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**Thank you for your attention!**